

H11AV1X, H11AV2X, H11AV3X  
H11AV1, H11AV2, H11AV3



**ISOCOM**  
COMPONENTS

**OPTICALLY COUPLED  
ISOLATOR  
PHOTOTRANSISTOR OUTPUT**



**APPROVALS**

- UL recognised, File No. E91231  
Package System "GG"
- **'X' SPECIFICATION APPROVALS**
  - VDE 0884 in 3 available lead form : -
    - STD
    - G form
    - SMD approved to CECC 00802
  - Certified to EN60950 by  
Nemko - Certificate No. P01102464

**DESCRIPTION**

The H11AV series of optically coupled isolators consist of infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

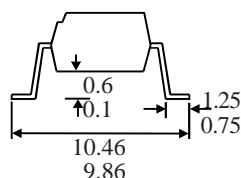
**FEATURES**

- Options :-  
10mm lead spread - add G after part no.  
Surface mount - add SM after part no.  
Tape&reel - add SMT&R after part no.
- High Isolation Voltage ( $5.3kV_{RMS}$ ,  $7.5kV_{PK}$ )
- High  $BV_{CEO}$  (70V min)
- All electrical parameters 100% tested
- Custom electrical selections available

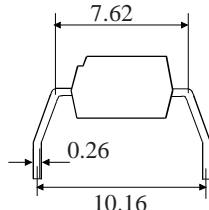
**APPLICATIONS**

- DC motor controllers
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

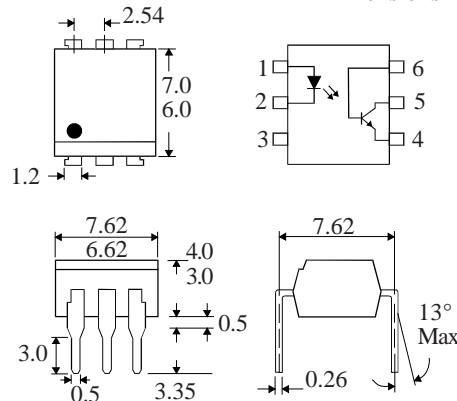
**OPTION SM  
SURFACE MOUNT**



**OPTION G**



**Dimensions in mm**



**ABSOLUTE MAXIMUM RATINGS  
(25°C unless otherwise specified)**

Storage Temperature \_\_\_\_\_ -55°C to +150°C  
Operating Temperature \_\_\_\_\_ -55°C to +100°C  
Lead Soldering Temperature  
(1/16 inch (1.6mm) from case for 10 secs) 260°C

**INPUT DIODE**

Forward Current \_\_\_\_\_ 60mA  
Reverse Voltage \_\_\_\_\_ 6V  
Power Dissipation \_\_\_\_\_ 105mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage  $BV_{CEO}$  \_\_\_\_\_ 70V  
Collector-base Voltage  $BV_{CBO}$  \_\_\_\_\_ 70V  
Emitter-collector Voltage  $BV_{ECO}$  \_\_\_\_\_ 6V  
Collector Current \_\_\_\_\_ 50mA  
Power Dissipation \_\_\_\_\_ 160mW

**POWER DISSIPATION**

Total Power Dissipation \_\_\_\_\_ 200mW  
(derate linearly 2.67mW/°C above 25°C)

**ISOCOM COMPONENTS 2004 LTD**

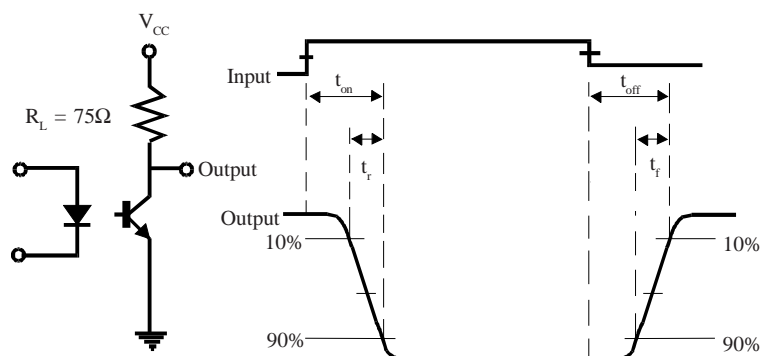
Unit 25B, Park View Road West,  
Park View Industrial Estate, Brenda Road  
Hartlepool, Cleveland, TS25 1UD  
Tel: (01429) 863609 Fax: (01429) 863581

**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage ( $V_F$ )		1.2	1.5	V	$I_F = 10\text{mA}$
	Reverse Current ( $I_R$ )			10	$\mu\text{A}$	$V_R = 6\text{V}$
Output	Collector-emitter Breakdown ( $BV_{CEO}$ ) ( note 2 )	70			V	$I_C = 1\text{mA}$
	Collector-base Breakdown ( $BV_{CBO}$ )	70			V	$I_C = 100\mu\text{A}$
	Emitter-collector Breakdown ( $BV_{ECO}$ )	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current ( $I_{CEO}$ )			50	nA	$V_{CE} = 10\text{V}$
Coupled	Current Transfer Ratio (CTR) H11AV1	100		300	%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	H11AV2	50			%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	H11AV3	20			%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			0.4	V	$20\text{mA } I_F, 2\text{mA } I_C$
	Input to Output Isolation Voltage $V_{ISO}$	5300 7500			$V_{RMS}$ $V_{PK}$	See note 1 See note 1
	Input-output Isolation Resistance $R_{ISO}$	$5 \times 10^{10}$			$\Omega$	$V_{IO} = 500\text{V}$ (note 1)
	Rise Time, $t_r$ Fall Time, $t_f$		2 2		$\mu\text{s}$ $\mu\text{s}$	$V_{CC} = 5\text{V}$ , fig 1 $I_F = 10\text{mA}, R_L = 75\Omega$

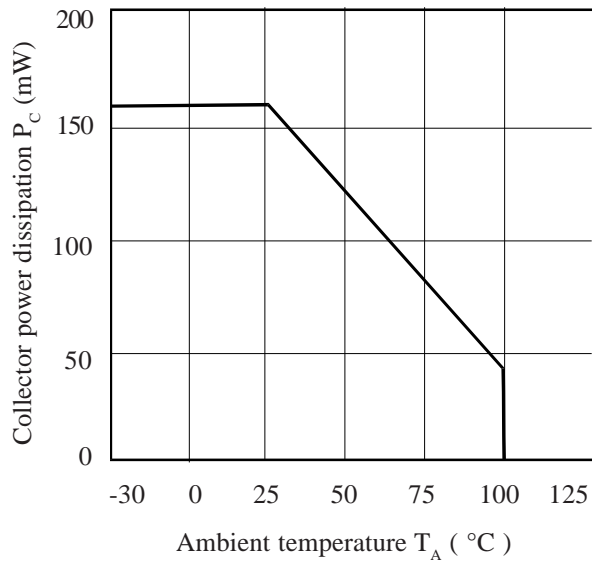
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

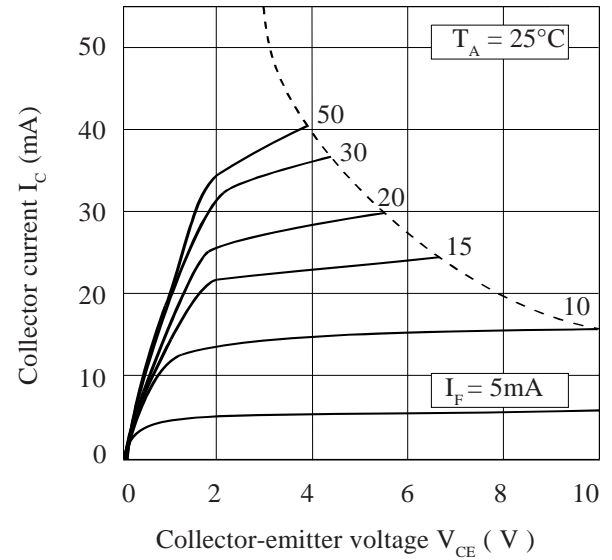


**FIG 1**

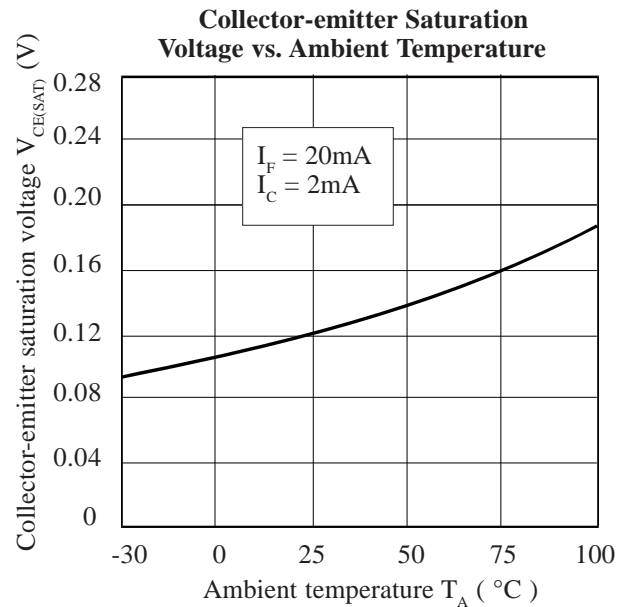
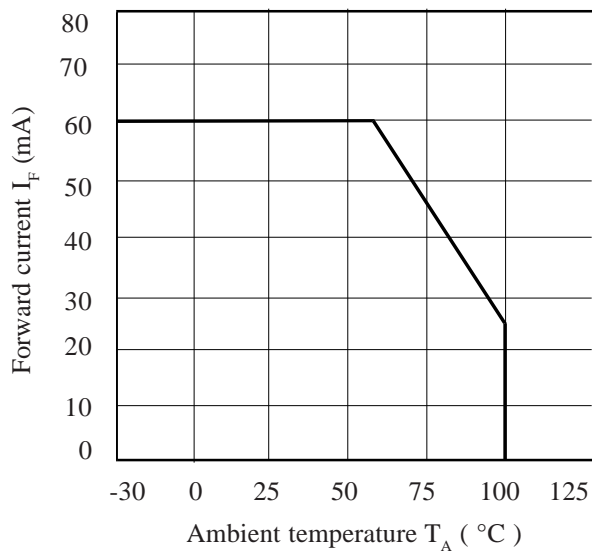
**Collector Power Dissipation vs. Ambient Temperature**



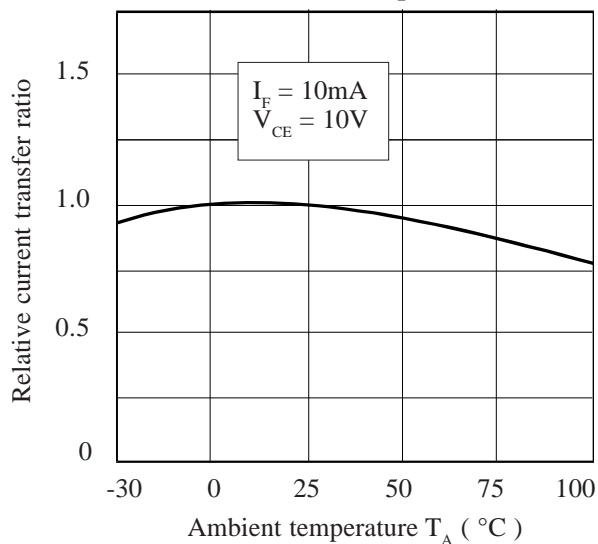
**Collector Current vs. Collector-emitter Voltage**



**Forward Current vs. Ambient Temperature**



**Relative Current Transfer Ratio vs. Ambient Temperature**



**Relative Current Transfer Ratio vs. Forward Current**

